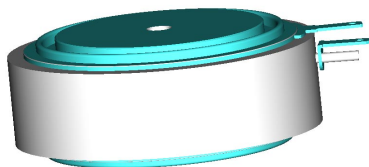


# GPTJ2046

## PHASE CONTROLLED SCR



High reliability operation  
DC power supply  
AC drives

**VOLTAGE UP TO** **2000 V**  
**AVERAGE CURRENT** **465 A**  
**SURGE CURRENT** **7 kA**

### BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
VRRM	Repetitive peak reverse voltage	2000 V
VRSM	Non-repetitive peak reverse voltage	2100 V
VDRM	Repetitive peak off-state voltage	2000 V
IDRM	Repetitive peak off-state current, max.	VDRM, single phase, half wave, T <sub>j</sub> = T <sub>jmax</sub>
IRRM	Repetitive peak reverse current, max.	VRRM, single phase, half wave, T <sub>j</sub> = T <sub>jmax</sub>

### ON-STATE CHARACTERISTICS

IT(AV)	Average on-state current	Sine wave, 180° conduction, Th = 55 °C	465 A
IT(RMS)	R.M.S. on-state current	Sine wave, 180° conduction, Th = 55 °C	730 A
ITSM	Surge on-state current	Non rep. half sine wave, 50 Hz, VR = 0 V, T <sub>j</sub> = T <sub>jmax</sub>	7 kA
I <sup>2</sup> t	I <sup>2</sup> t for fusing coordination		245 kA <sup>2</sup> s
VT(TO)	Threshold voltage	T <sub>j</sub> = T <sub>jmax</sub>	1.1 V
r <sub>T</sub>	On-state slope resistance	T <sub>j</sub> = T <sub>jmax</sub>	0.89 mΩ
VTM	Peak on-state voltage, max	On-state current I <sub>T</sub> = 1000 A, T <sub>j</sub> = 25 °C	1.82 V
I <sub>H</sub>	Holding current, max	T <sub>j</sub> = 25 °C	150 mA
I <sub>L</sub>	Latching current, typ	T <sub>j</sub> = 25 °C	300 mA

### TRIGGERING CHARACTERISTICS

V <sub>GT</sub>	Gate trigger voltage	T <sub>j</sub> = 25 °C, V <sub>D</sub> = 5 V	3 V
I <sub>GT</sub>	Gate trigger current	T <sub>j</sub> = 25 °C, V <sub>D</sub> = 5 V	300 mA
V <sub>GD</sub>	Non-trigger voltage	V <sub>D</sub> = 67% VRRM, T <sub>j</sub> = T <sub>jmax</sub>	0.25 V
P <sub>GM</sub>	Peak gate power dissipation	Pulse width 0.5 ms	100 W
P <sub>G(AV)</sub>	Average gate power dissipation		5 W
I <sub>FGM</sub>	Peak gate current		20 A
V <sub>FGM</sub>	Peak gate voltage (forward)		10 V
V <sub>RGM</sub>	Peak gate voltage (reverse)		3 V

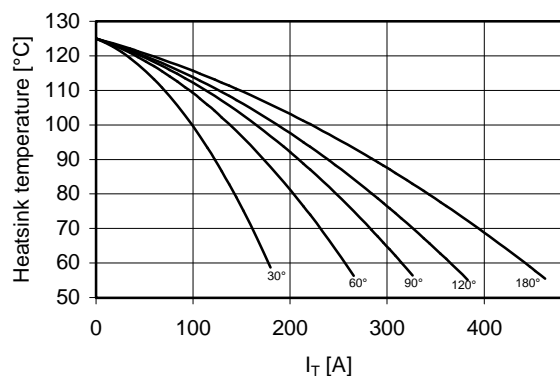
### SWITCHING CHARACTERISTICS

di/dt	Critical rate of rise of on-state current	T <sub>j</sub> = T <sub>jmax</sub>	200 A/μs
dV/dt	Critical rate of rise of off-state voltage	T <sub>j</sub> = T <sub>jmax</sub>	1000 V/μs
t <sub>q</sub>	Turn-off time, typ	T <sub>j</sub> = T <sub>jmax</sub> , I <sub>T</sub> = 320 A, di/dt = -12.5 A/μs VR = 100 V, VD = 67% VDRM, dV/dt = 20 V/μs	250 μs

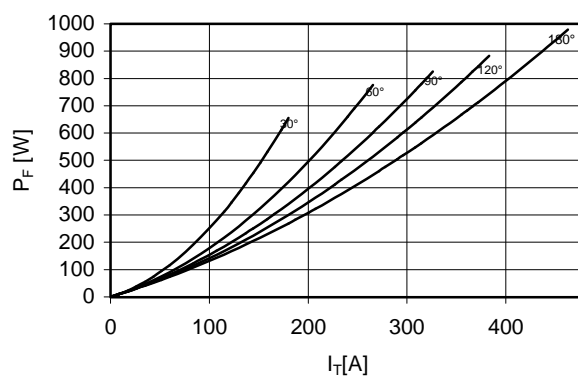
### THERMAL AND MECHANICAL CHARACTERISTICS

R <sub>th(j-c)</sub>	Thermal resistance (junction to case)	Double side cooled	0.056 °C/W
R <sub>th(c-h)</sub>	Thermal resistance (case to heatsink)	Double side cooled	0.015 °C/W
T <sub>jmax</sub>	Max operating junction temperature		125 °C
T <sub>stg</sub>	Storage temperature		-40 / 125 °C
F	Clamping force ± 10%		7 kN
	Mass		180 g

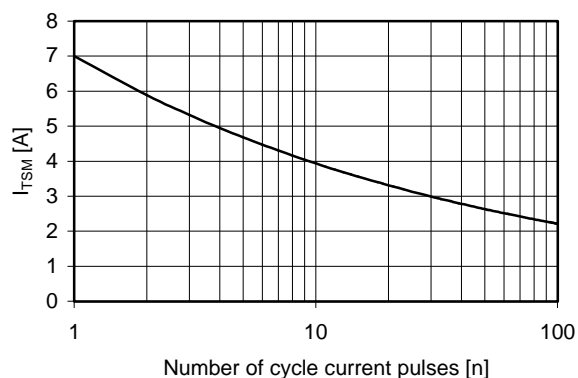
Current rating - sine wave



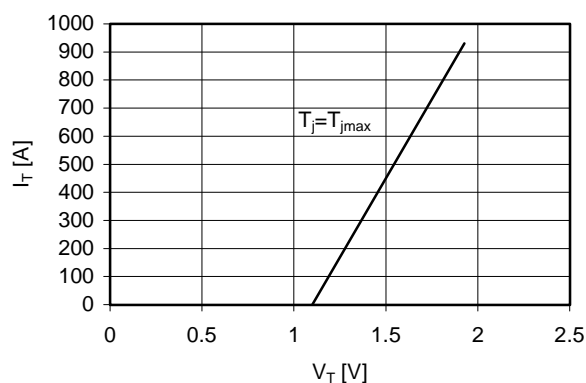
Power loss - sine wave



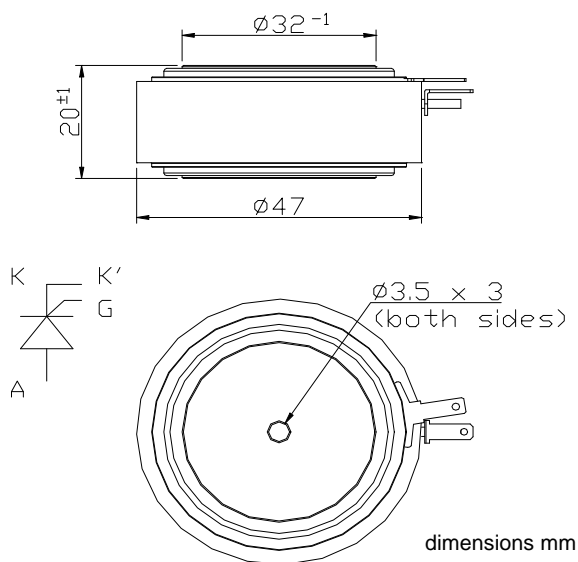
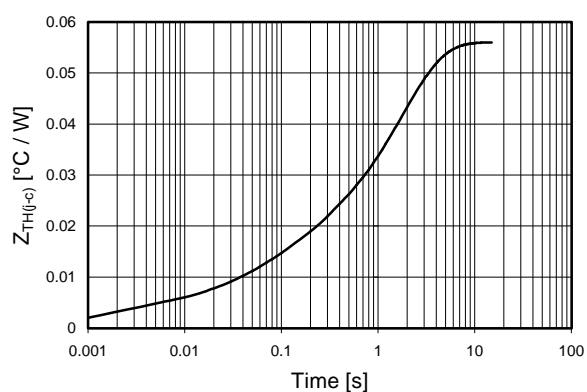
Maximum surge current  
d.s. cooled



On-state voltage drop



Thermal impedance (j-c)



In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.